
Lecture12

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Potential energy

- In the case of the infinite potential well, the potential energy is 0 eV.
 - Of course, in the realistic case, the potential energy is provided from the Poisson equation.
 - When the electro potential, $\phi(z)$, is given, the potential energy is written as

$$V(z) = -q\phi(z) + (E_c - E_i)$$

$E_c - E_i$: Constant for a given material

Schrödinger equation

- For the z-directional Schrodinger equation,

- We have the following form:

$$-\frac{\hbar^2}{2m_{zz}} \frac{d^2}{dz^2} \psi_{z,n}(z) + V(z) \psi_{z,n}(z) = E_{z,n} \psi_{z,n}(z)$$

- After a simple manipulation,

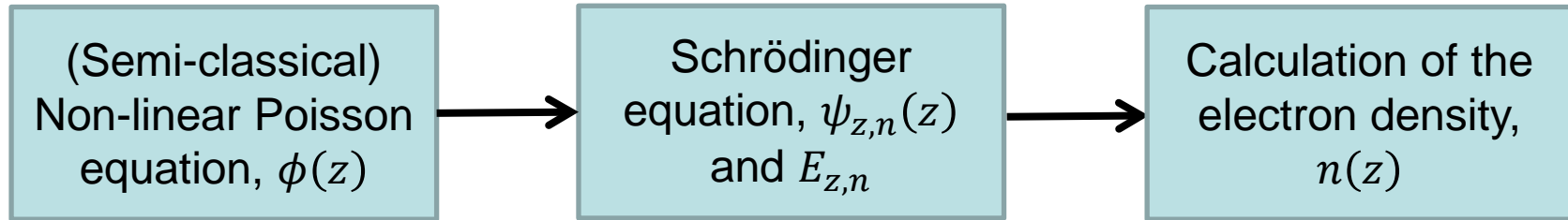
$$\frac{d^2}{dz^2} \psi_{z,n}(z) - \frac{2m_{zz}}{\hbar^2} V(z) \psi_{z,n}(z) = -\frac{2m_{zz}}{\hbar^2} E_{z,n} \psi_{z,n}(z)$$

- Discretized version

$$\psi_{z,n,i+1} - 2\psi_{z,n,i} + \psi_{z,n,i-1} - \frac{2m_{zz}}{\hbar^2} V(z_i)(\Delta z)^2 \psi_{z,n,i} = -\frac{2m_{zz}}{\hbar^2} E_{z,n}(\Delta z)^2 \psi_{z,n,i}$$

Simulation flow

- Anyway, we need the initial solution.
 - It can be obtained from the semi-classical simulation.
 - Then, under the given potential energy, we can calculate the electron density.



- Of course, the electron density is not fully consistent with the Poisson equation. It should be improved later.

MATLAB example (1)

- Defining variables

```
h = 6.626176e-34; % Planck constant, J s
hbar = h / (2*pi); % Reduced Planck constant, J s
q = 1.602192e-19; % Elementary charge, C
m0 = 9.109534e-31; % Electron rest mass, kg
k_B = 1.380662e-23; % Boltzmann constant, J/K
eps0 = 8.854187817e-12; % Vacuum permittivity, F/m
T = 300.0; % Temperature, K
thermal = k_B*T/q; % Thermal voltage, V
mxx = 0.19; myy = 0.19; mzz = 0.91; % Masses, m0
Deltaz = 0.1e-9; % 0.1 nm spacing
Nz = 61; % 6 nm thick
z = Deltaz*transpose([0:Nz-1]); % real space, m
interface1 = 6; % At z=0.5 nm
interface2 = 56; % At z=5.5 nm
eps_si = 11.7; eps_ox = 3.9; % Relative permittivity
Nacc = 1e24; % 1e18 /cm^3
ni = 1.075e16; % 1.075e10 /cm^3
coef = Deltaz*Deltaz*q/eps0;
Ec_Ei = 0.561004; % E_c - E_i, eV
```

MATLAB example (2)

- Semi-classical nonlinear Poisson solver

```
phi = zeros(Nz,1);
phi(:,1) = 0.33374;
for newton=1:10
    res = zeros(Nz,1);
    Jaco = sparse(Nz,Nz);
    res(1,1) = phi(1,1) - 0.33374;
    Jaco(1,1) = 1.0;
    res(Nz,1) = phi(Nz,1) - 0.33374;
    Jaco(Nz,Nz) = 1.0;
    for ii=2:Nz-1
        if (ii< interfacer1 || ii> interface2)
            res(ii,1) = eps_ox*phi(ii+1,1) - 2*eps_ox*phi(ii,1) + eps_ox*phi(ii-1,1);
            Jaco(ii,ii-1) = eps_ox; Jaco(ii,ii) = -2*eps_ox; Jaco(ii,ii+1) = eps_ox;
        elseif (ii==interfacer1)
            res(ii,1) = eps_si*phi(ii+1,1) - (eps_si+eps_ox)*phi(ii,1) + eps_ox*phi(ii-1,1);
            Jaco(ii,ii-1) = eps_ox; Jaco(ii,ii) = -(eps_si+eps_ox); Jaco(ii,ii+1) = eps_si;
        elseif (ii==interface2)
            res(ii,1) = eps_ox*phi(ii+1,1) - (eps_ox+eps_si)*phi(ii,1) + eps_si*phi(ii-1,1);
            Jaco(ii,ii-1) = eps_si; Jaco(ii,ii) = -(eps_ox+eps_si); Jaco(ii,ii+1) = eps_ox;
        else
            res(ii,1) = eps_si*phi(ii+1,1) - 2*eps_si*phi(ii,1) + eps_si*phi(ii-1,1);
            Jaco(ii,ii-1) = eps_si; Jaco(ii,ii) = -2*eps_si; Jaco(ii,ii+1) = eps_si;
        end
    end
end
```

MATLAB example (3)

- Semi-classical nonlinear Poisson solver (continued)

```
for ii=interfacel:interface2
    if      (ii==interfacel)
        res(ii,1) = res(ii,1) - coef*(Nacc+ni*exp(phi(ii,1)/thermal))*0.5;
        Jaco(ii,ii) = Jaco(ii,ii) - coef*ni*exp(phi(ii,1)/thermal)/thermal*0.5;
    elseif (ii==interface2)
        res(ii,1) = res(ii,1) - coef*(Nacc+ni*exp(phi(ii,1)/thermal))*0.5;
        Jaco(ii,ii) = Jaco(ii,ii) - coef*ni*exp(phi(ii,1)/thermal)/thermal*0.5;
    else
        res(ii,1) = res(ii,1) - coef*(Nacc+ni*exp(phi(ii,1)/thermal));
        Jaco(ii,ii) = Jaco(ii,ii) - coef*ni*exp(phi(ii,1)/thermal)/thermal;
    end
end
update = Jaco \ (-res);
phi = phi + update;
end
```

MATLAB example (3)

- Schrödinger solver

- Now we have the electrostatic potential. The potential energy is

`V = q*Ec_Ei - q*phi; % Potential energy, J`

- Only for bulk silicon nodes, the Hamiltonian is constructed.

`Nbulk = interface2-interface1-1; % Number of bulk silicon nodes`

`Hamil = zeros(Nbulk,Nbulk);`

`Hamil(1,1) = -2; Hamil(1,2) = 1;`

`for ii=2:Nbulk-1`

`Hamil(ii,ii+1) = 1;`

`Hamil(ii,ii) = -2;`

`Hamil(ii,ii-1) = 1;`

`end`

`Hamil(Nbulk,Nbulk) = -2; Hamil(Nbulk,Nbulk-1) = 1;`

MATLAB example (4)

- Schrödinger solver (continued)

- The potential energy is added.

```
for ii=1:Nbulk
    Hamil(ii,ii) = Hamil(ii,ii) -2*mzz*m0*(Deltaz/hbar)^2*V(ii+interfacel,1);
end
```

- Get the solution.

```
[eigenvectors,eigenvalues] = eig(Hamil);
```

- Scale the eigenenergies.

```
Ez = diag(eigenvalues)/(-2*mzz*m0*(Deltaz/hbar)^2); % Eigenenergy, J
```

- The wavefunction should be scaled.

Normalization of $\psi_{z,n}(z)$

- Its normalization condition

- Intergration form

$$\int_0^{L_z} dz |\psi_{z,n}(z)|^2 = 1$$

- Discretized version

$$\sum_i \Delta z |\psi_{z,n,i}|^2 = 1$$

- Eigenfunctions should be normalized accordingly.

Modified MATLAB code (1)

- Defining variables (1)

```
h = 6.626176e-34; % Planck constant, J s
hbar = h / (2*pi); % Reduced Planck constant, J s
q = 1.602192e-19; % Elementary charge, C
m0 = 9.109534e-31; % Electron rest mass, kg
k_B = 1.380662e-23; % Boltzmann constant, J/K
eps0 = 8.854187817e-12; % Vacuum permittivity, F/m
T = 300.0; % Temperature, K
thermal = k_B*T/q; % Thermal voltage, V
```

Modified MATLAB code (2)

- Defining variables (2)

```
Lx = 100e-9; Ly = 100e-9; % Lengths, m
mxx = 0.19; myy = 0.19; mzz = 0.91; % Masses, m0
Deltaz = 0.1e-9; % 0.1 nm spacing
Nz = 61; % 6 nm thick
z = Deltaz*transpose([0:Nz-1]); % real space, m
interfacel = 6; % At z=0.5 nm
interface2 = 56; % At z=5.5 nm
eps_si = 11.7; eps_ox = 3.9; % Relative permittivity
Nacc = 1e24; % 1e18 /cm^3
ni = 1.075e16; % 1.075e10 /cm^3
coef_Poi = Deltaz*Deltaz*q/eps0;
coef_Sch = 2*Lx*Ly/(2*pi)*sqrt(mxx*myy)*m0/(hbar^2)*(k_B*T);
Ec_Ei = 0.561004; % E_c - E_i, eV
```

Modified MATLAB code (3)

- Semi-classical nonlinear Poisson solver

```
phi = zeros(Nz,1);  
phi(:,1) = 0.33374;  
for newton=1:10  
    res = zeros(Nz,1);  
    Jaco = sparse(Nz,Nz);  
    res(1,1) = phi(1,1) - 0.33374;  
    Jaco(1,1) = 1.0;  
    res(Nz,1) = phi(Nz,1) - 0.33374;  
    Jaco(Nz,Nz) = 1.0;
```

Modified MATLAB code (4)

- Semi-classical nonlinear Poisson solver

```
for ii=2:Nz-1
    if (ii< interface1 || ii> interface2)
        res(ii,1) = eps_ox*phi(ii+1,1) - 2*eps_ox*phi(ii,1) + eps_ox*phi(ii-1,1);
        Jaco(ii,ii-1) = eps_ox; Jaco(ii,ii) = -2*eps_ox; Jaco(ii,ii+1) = eps_ox;
    elseif (ii==interface1)
        res(ii,1) = eps_si*phi(ii+1,1) - (eps_si+eps_ox)*phi(ii,1) + eps_ox*phi(ii-1,1);
        Jaco(ii,ii-1) = eps_ox; Jaco(ii,ii) = -(eps_si+eps_ox); Jaco(ii,ii+1) = eps_si;
    elseif (ii==interface2)
        res(ii,1) = eps_ox*phi(ii+1,1) - (eps_ox+eps_si)*phi(ii,1) + eps_si*phi(ii-1,1);
        Jaco(ii,ii-1) = eps_si; Jaco(ii,ii) = -(eps_ox+eps_si); Jaco(ii,ii+1) = eps_ox;
    else
        res(ii,1) = eps_si*phi(ii+1,1) - 2*eps_si*phi(ii,1) + eps_si*phi(ii-1,1);
        Jaco(ii,ii-1) = eps_si; Jaco(ii,ii) = -2*eps_si; Jaco(ii,ii+1) = eps_si;
    end
end
end
```

Modified MATLAB code (5)

- Semi-classical nonlinear Poisson solver (continued)

```
for ii=interface1:interface2
    if      (ii==interface1)
        res(ii,1) = res(ii,1) - coef_Poi*(Nacc+ni*exp(phi(ii,1)/thermal))*0.5;
        Jaco(ii,ii) = Jaco(ii,ii) - coef_Poi*ni*exp(phi(ii,1)/thermal)/thermal*0.5;
    elseif (ii==interface2)
        res(ii,1) = res(ii,1) - coef_Poi*(Nacc+ni*exp(phi(ii,1)/thermal))*0.5;
        Jaco(ii,ii) = Jaco(ii,ii) - coef_Poi*ni*exp(phi(ii,1)/thermal)/thermal*0.5;
    else
        res(ii,1) = res(ii,1) - coef_Poi*(Nacc+ni*exp(phi(ii,1)/thermal));
        Jaco(ii,ii) = Jaco(ii,ii) - coef_Poi*ni*exp(phi(ii,1)/thermal)/thermal;
    end
end
update = Jaco \ (-res);
phi = phi + update;
end
```

Modified MATLAB code (6)

- Schrödinger solver

```
V = q*Ec_Ei - q*phi; % Potential energy, J
Nbulk = interface2-interface1-1; % Number of bulk silicon nodes
Hamil = zeros(Nbulk,Nbulk);
Hamil(1,1) = -2; Hamil(1,2) = 1;
for ii=2:Nbulk-1
    Hamil(ii,ii+1) = 1;
    Hamil(ii,ii) = -2;
    Hamil(ii,ii-1) = 1;
end
Hamil(Nbulk,Nbulk) = -2; Hamil(Nbulk,Nbulk-1) = 1;
for ii=1:Nbulk
    Hamil(ii,ii) = Hamil(ii,ii) -2*mzz*m0*(Deltaz/hbar)^2*V(ii+interface1,1);
end
```


MATLAB example (1)

- Continued discussion

- Get the solution.

```
[eigenvectors,eigenvalues] = eig(Hamil);
```

- Scale the eigen-energies.

```
scaledEz = diag(eigenvalues)/(-2*mzz*m0*(Deltaz/hbar)^2); % Eigenenergy, J
```

- Sort the eigen-energies.

```
[sortedEz,sortedIndex] = sort(scaledEz);
```

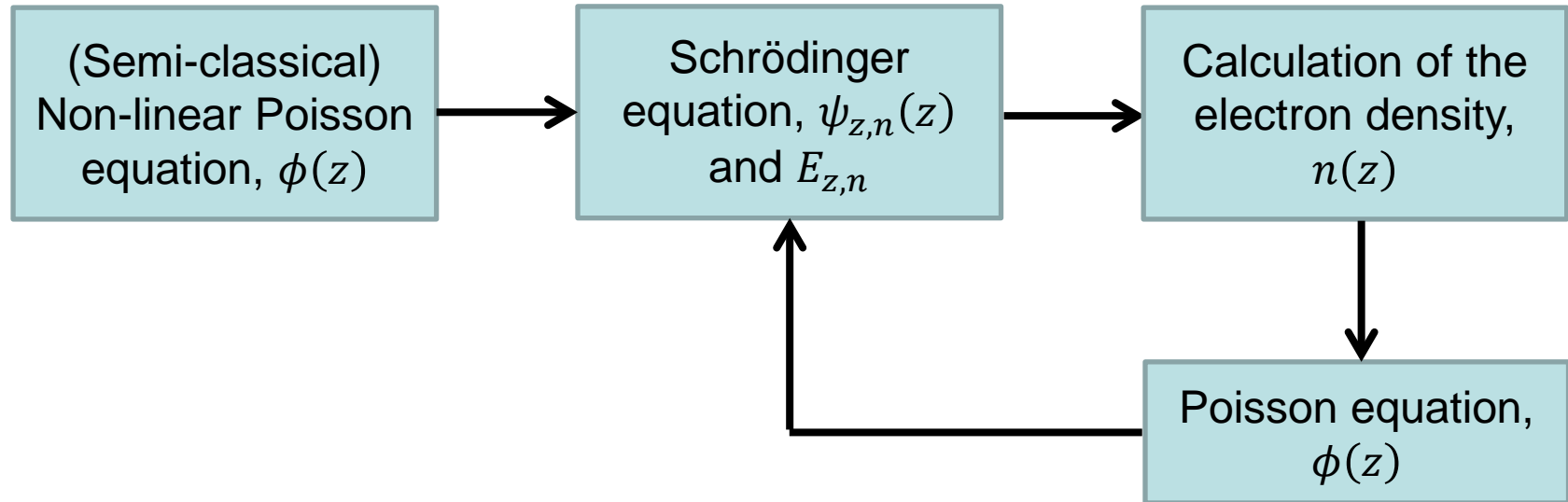
MATLAB example (2)

- Calculation of the electron density

```
nSubband = 10;
elec = zeros(Nz,1); % Electron density, /m^3
totalNumber = 0;
for n=1:nSubband
    Ez = sortedEz(n,1);
    wavefunction2 = eigenvectors(:,sortedIndex(n)).^2;
    normalization = sum(wavefunction2)*Deltaz;
    wavefunction2 = wavefunction2 / normalization;
    subbandNumber = coef_Sch*log(1+exp(-Ez/(k_B*T)));
    totalNumber = totalNumber + subbandNumber;
    elec(interface1+1:interface2-1,1) = elec(interface1+1:interface2-1,1) +
    1/(Lx*Ly)*wavefunction2*subbandNumber;
end
```

Simulation flow

- Self-consistency
 - The electron density is not consistent with the Poisson equation.
 - Better way?



6 valleys in silicon

- Up to now, we have considered only one band.
 - In silicon, we need to consider three valley pairs.
 - They can be characterized by (for a certain channel direction)
 $m_{xx} = 0.91m_0, m_{yy} = 0.19m_0, m_{zz} = 0.19m_0$
 $m_{xx} = 0.19m_0, m_{yy} = 0.91m_0, m_{zz} = 0.19m_0$
 $m_{xx} = 0.19m_0, m_{yy} = 0.19m_0, m_{zz} = 0.91m_0$
 - Each of them has two-fold degeneracy.

MATLAB example

- Pseudocode

(Defining constants. Copy-and-paste)

(Semi-classical nonlinear Poisson equation. Copy-and-paste)

```
for iNewton = 1:20
```

```
    totalNumber = 0;
```

```
    elec = zeros(Nz,1); % Electron density, /m^3
```

```
    for iValley = 1:3
```

```
        mass = ones(3)*0.19;
```

```
        mass(iValley) = 0.91;
```

```
        coef_Sch = 2*Lx*Ly/(2*pi)*sqrt(mass(1)*mass(2))*m0/(hbar^2)*(k_B*T);
```

```
        (Schrodinger solver. Now mzz becomes mass(3).)
```

```
        (Calculation of electron density. Add it to elec.)
```

```
    end
```

```
    (Poisson equation)
```

```
end
```